

Complete Single Supply 12-Bit Voltage Output DAC in SO-8

FEATURES

- 8-Pin SO Package
- Buffered Voltage Output
- Built-In 2.048V Reference
- 500uV/LSB with 2.048V Full Scale
- 1/2 LSB Max DNL Error
- Guaranteed 12-Bit Monotonic
- Three-Wire Cascadable Serial Interface
- Wide Single Supply Range: V_{CC} = 4.75V to 15.75V
- Low Power: I_{CC} Typ = 350µA with 5V Supply

APPLICATIONS

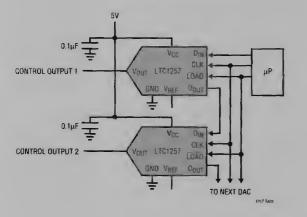
- Digital Offset/Gain Adjustment
- Industrial Process Control
- Automatic Test Equipment

DESCRIPTION

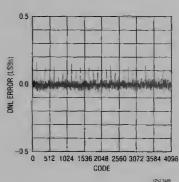
The LTC1257 is a complete single supply, 12-bit voltage output D/A converter (DAC) in an SO-8 package. The LTC1257 includes an output buffer amplifier, 2.048V voltage reference and an easy to use three-wire cascadable serial interface. An external reference can be used to override the internal reference and extend the output voltage range to 12V. The power supply current is a low 350µA when operating from a 5V supply, making the LTC1257 ideal for battery-powered applications. The space-saving 8-pin SO package and operation with no external components provide the smallest 12-bit D/A system available.

TYPICAL APPLICATION

Daisy Chained Control Outputs



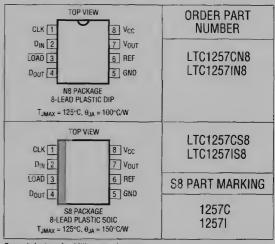
Differential Nonlinearity vs Input Code



ARSOLUTE MAXIMUM RATINGS

V _{CC} to GND	0.5V to 16.5V
TTL Input Voltage	$-0.5V$ to $V_{CC} + 0.5V$
V _{OUT}	$-0.5V$ to $V_{CC} + 0.5V$
REF	$-0.5V$ to $V_{CC} + 0.5V$
Operating Temperature Range	
LTC1257C	0°C to 70°C
LTC12571	40°C to 85°C
Maximum Junction Temperature	
Plastic Package	65°C to 125°C
Storage Temperature Range	65°C to 150°C
Lead Temperature (Soldering, 10 se	ec) 300°C

PACKAGE/ORDER INFORMATION



Consult factory for Military grade parts.

ELECTRICAL CHARACTERISTICS V_{CC} = 4.75V to 15.75V, internal or external reference

 $(2.475V \le V_{REF} \le V_{CC} - 2.7V)$, $I_{OUT} \le 2mA$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS	
DAC								
	Resolution		•	12			Bits	
DNL	Differential Nonlinearity	Guaranteed Monotonic	•			±0.5	LSB	
INL	Integral Nonlinearity	LTC1257C LTC1257!				±3.5 ±4.0	LSB LSB	
OFF	Offset Error	When Using Internal Reference, LTC1257C When Using Internal Reference, LTC12571				±8 ±10	LSB LSB	
		When Using External Reference, LTC1257C When Using External Reference, LTC12573	•			±4 ±5	mV mV	
OFFTC	Offset Error Tempco	When Using Internal Reference (Note 1) When Using External Reference (Note 1)	•		±0.02 ±15	±0.066 ±30	LSB/°C µV/°C	
FSE	Full-Scale Error		•		0.5	±2	LSB	
FSETC	Full-Scale Error Tempco	(Note 1)	•		±0.01	±0.02	LSB/°C	
Reference								
	Reference Output Voltage	I _{OUT} = 0, LTC1257C I _{OUT} = 0, LTC1257I		2.028 2.018	2.048	2.068 2.078	V	
	Reference Output Tempco	lout = 0	•		±0.06		LSB/°C	
	Reference Line Regulation	I _{OUT} = 0, LTC1257C I _{OUT} = 0, LTC1257I	•			±0.4 ±0.7	LSB/V LSB/V	
	Reference Load Regulation	0 ≤ I _{OUT} ≤ 100μA	•			±1	LSB	
	Reference Input Range	V _{CC} > V _{REF} + 2.7V	•	2.475		12	٧	
	Reference Input Resistance		•	8	14	18	kΩ	
	Reference Input Capacitance	(Note 1)			15		pF	
	Short-Circuit Current	Vour Shorted to GND	•			90	mA	

ELECTRICAL CHARACTERISTICS $V_{CC} = 4.75V$ to 15.75V, internal or external reference (2.475V \leq $V_{REF} \leq$ $V_{CC} - 2.7V$), $I_{OUT} \leq$ 2mA, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Power Su	pply						
V _{CC}	Positive Supply Voltage	For Specified Performance	•	4.75		15.75	V
lcc	Supply Current	$4.75V \le V_{CC} \le 5.25V$ $4.75V \le V_{CC} \le 15.75V$	•		350 800	600 1500	μA μA
Op Amp D	C Performance			100			
	Short-Circuit Current Low	V _{OUT} Shorted to GND	•			60	m.A
	Short-Circuit Current High	V _{OUT} Shorted to V _{CC}	•			60	mA
	Output Impedance to GND	Input Code = 0	•		150	300	Ω
AC Perfori	mance						
	Voltage Output Slew Rate	5kΩ in Parallel with 100pF	•	1.0			V/µs
	Voltage Output Settling Time	To ±1/2LSB, 5kΩ in Parallel with 100pF	•			6	μs
	Digital Feedthrough	(Notes 1,2)			50		nV/s
Digital I/O							
V _{IH}	Digital Input High Voltage		•	2.4			V
VIL	Digital Input Low Voltage		•			0.8	V
VoH	Digital Output High Voltage	I _{OUT} = −1mA, D _{OUT} Only	•	V _{CC} - 1			V
VOL	Digital Output Low Voltage	I _{OUT} = 1mA, D _{OUT} Only		0.4			V
LEAK	Digital Input Leakage	V _{IN} = GND to V _{CC}	•			±10	μА
CiN	Digital Input Capacitance	(Note 1)	•			10	pF
Switching	(Note 1)						
t1	D _{IN} Valid to CLK Setup		•	150			ns
t2	D _{IN} Valid to CLK Hold		•	0			ns
13	CLK High Time		•	350			ns
t4	CLK Low Time		•	350			ns
t5	LOAD Pulse Width		•	150			RS
t6	LSB CLK to LOAD		•	0			ns
t7	LOAD High to CLK		•	0			ns
18	D _{OUT} Output Delay	C _{LOAD} = 15pF	•			150	ns
f _{CLK}	Maximum Clock Frequency					1.4	MHz

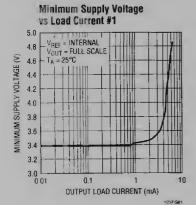
The o denotes specifications which apply over the full operating temperature range.

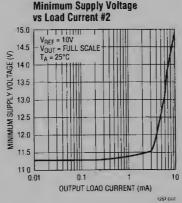
Note 1: Guaranteed by design; not subject to test.

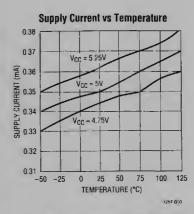
Note 2: DAC switched from all 1s to all 0s, and all 0s to all 1s code.

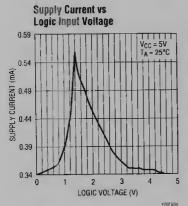


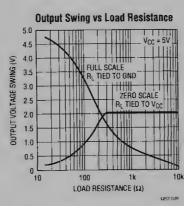
TYPICAL PERFORMANCE CHARACTERISTICS

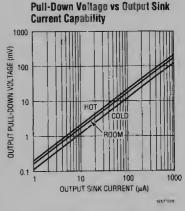


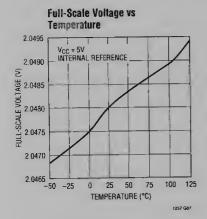


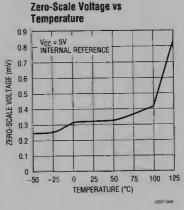


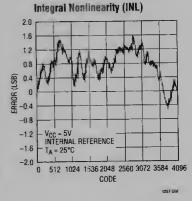




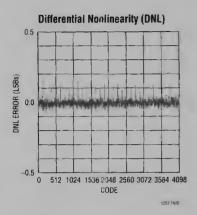


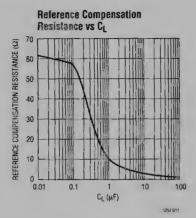


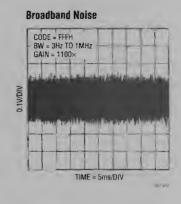




TYPICAL PERFORMANCE CHARACTERISTICS







PIN FUNCTIONS

CLK: The TTL level input for the serial interface clock.

 D_{IN} : The TTL level input for the serial interface data. Data on the D_{IN} pin is latched into the shift register on the rising edge of the serial clock.

LOAD: The TTL level input for the serial interface load control. Data is loaded from the shift register into the DAC register, thus updating the DAC output when LOAD is pulled low. The DAC register is transparent as long as LOAD is held low.

 D_{OUT} : The output of the shift register which becomes valid on the rising edge of the serial clock. The D_{OUT} pin is driven from GND to V_{CC} by an internal CMOS inverter. Multiple LTC1257s may be cascaded by connecting the D_{OUT} pin to the D_{IN} pin of the next chip.

GND: Ground.

REF: The output of the 2.048V reference and the input to the DAC resistor ladder. An external reference with voltage from 2.475V to $V_{CC}-2.7V$ may be used to override the internal reference.

 V_{DUT} : The buffered DAC output is capable of sourcing 2mA over temperature while pulling within 2.7V of V_{CC} . The output will pull to ground through an internal 200 Ω equivalent resistance.

V_{CC}: The positive supply input. $4.75V \le V_{CC} \le 15.75V$. Requires a bypass capacitor to ground.

BEFINITIONS

LSB: The least significant bit or the ideal voltage difference between two successive codes.

 $LSB = (V_{FS} - V_{DS})/2^{n} - 1$

n = The number of digital input bits

 V_{OS} = The zero code error or offset of the DAC

V_{FS} = The full-scale output voltage of the DAC measured when all bits are set to 1

Resolution: The resolution is the number of DAC output states (2ⁿ) that divide the full-scale range. The resolution does not imply linearity.

INL: End-point integral nonlinearity is the maximum deviation from a straight line passing through the end-points of the DAC transfer curve. Because the part operates from a single supply and the output cannot go below ground, the linearity is measured between full-scale and the first code that guarantees a positive output. The INL error at a given input code is calculated as follows:

 $INL = (V_{OUT} - V_{IDEAL})/LSB$ $V_{IDEAL} = (Code \times LSB) + V_{OS}$

V_{OUT} = The output voltage of the DAC measured at the given input code

DNL: Differential nonlinearity is the difference between the measured change and the ideal 1LSB change between any two adjacent codes. The DNL error between any two codes is calculated as follows:

DNL = $(\Delta V_{OUT} - LSB)/LSB$

ΔV_{OUT} = The measured voltage difference between two adjacent codes

Offset Error: The theoretical voltage at the output when the DAC is loaded with all zeros. The output amplifier can have a true negative offset, but because the part is operated from a single supply, the output cannot go below ground. If the offset is negative, the output will remain near OV resulting in the transfer curve shown in Figure 1.



Figure 1. Effect of Negative Offset

The offset of the part is measured at the first code that produces an output voltage 0.5LSB greater than the previous code:

$$V_{OS} = V_{OUT} - [(Code \times V_{FS})/(2^n - 1)]$$

Full-Scale Error: Full-scale error is the difference between the ideal and measured DAC output voltages with all bits set to one (Code = 4095). The full-scale error includes the offset error and is calculated as follows:

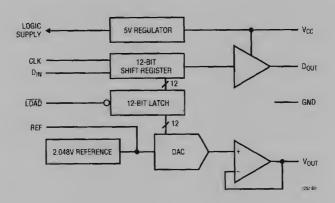
 $FSE = (V_{OUT} - V_{IDEAL})/LSB$

 $V_{IDEAL} = [V_{REF} \times (1 - 2^{-n})] - V_{OS}$

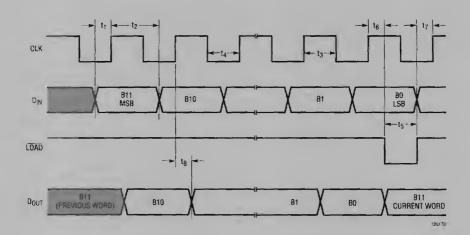
V_{REF} = The reference voltage, either internal or external

Digital Feedthrough: The glitch that appears at the analog output caused by AC coupling from the digital inputs when they change state. The area of the glitch is specified in nV × sec.

BLOCK DIAGRAM



TIMING DIAGRAM



OPERATION

Serial Interface

The data on the D_{IN} input is loaded into the shift register on the rising edge of the clock. The MSB is loaded first and the LSB last. The DAC register loads the data from the shift register when \overline{LOAD} is pulled low, and remains transparent until \overline{LOAD} is pulled high and the data is latched.

An internal 5V regulator provides the supply for the digital logic. By limiting the internal digital signal swings to 5V, digital noise is reduced. The buffered output of the 12-bit shift register is available on the D_{OUT} pin which will swing from GND to $V_{CC}. \label{eq:condition}$

Multiple LTC1257s may be daisy chained together by connecting the D_{OUT} pin to the D_{IN} pin of the next chip, while the clock and load signals remain common to all chips in the daisy chain. The serial data is clocked to all of the chips, then the \overline{LOAD} signal is pulled low to update all of them simultaneously. The maximum clocking rate is 1.4MHz.

Reference

The LTC1257 includes an internal 2.048V reference, making 1LSB equal to $500\mu V$. The internal reference output is turned off when the pin is forced above the reference voltage, allowing an external reference to be connected to the reference pin. The external reference must be greater than 2.475V and less than $V_{CC} = 2.7V$, and be capable of driving the 10k minimum DAC resistor ladder.

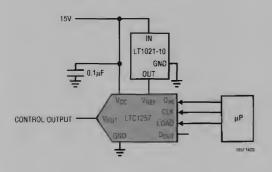
If the reference output is driving a large capacitive load, a series resistor must be added to insure stability. For any capacitive load greater than $1\mu F$, a 10Ω series resistor will suffice.

Voltage Output

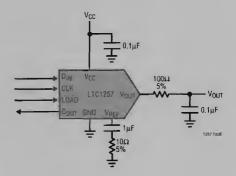
The LTC1257 voltage output is able to pull within 2.7V of V_{CC} while sourcing 2mA. A internal NMOS transistor with a 200Ω equivalent impedance pulls the output to ground. The output is protected against short circuits and is able to drive up to a 500pF capacitive load without oscillation. If digital noise on the output causes a problem, a simple 100Ω , $0.1\mu F$ RC circuit can be used to filter the noise.

TYPICAL APPLICATIONS

DAC with External Reference

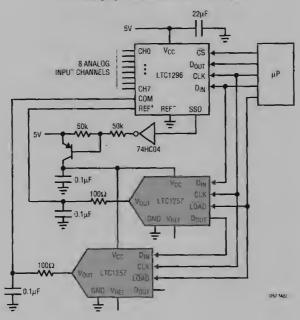


Filtering V_{RFF} and V_{OUT}

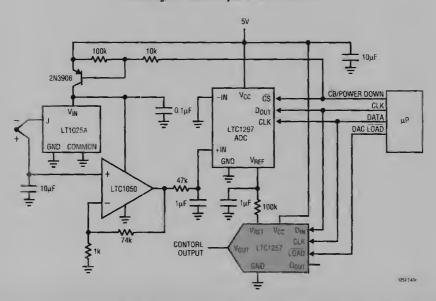


TYPICAL APPLICATIONS

Auto Ranging 8-Channel ADC with Shutdown

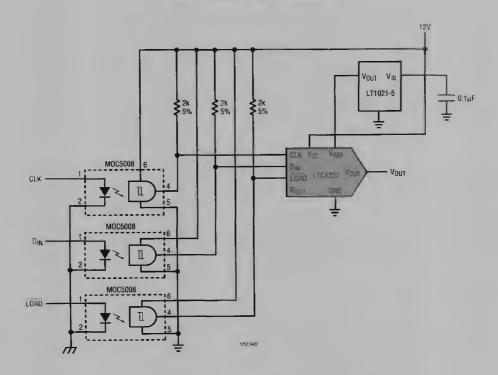


12-Bit Single 5V Control System with Shutdown



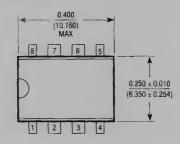
TYPICAL APPLICATIONS

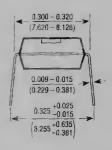
Driving LTC1257 with Opto-Isolators

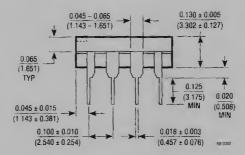


PACKAGE DESCRIPTION Dimensions in inches (millimeters) unless otherwise noted.

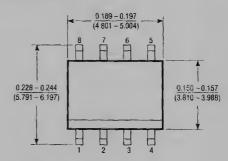
N8 Package 8-Lead Plastic DIP

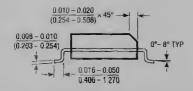


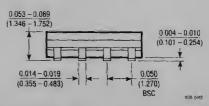




S8 Package 8-Lead Plastic SOIC









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